TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCES)

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POWER AMPLIFIER APPLICATIONS

POWER SWITCHING APPLICATIONS

• Low Saturation Voltage : V_{CE} (sat) = −0.5V (Max.)

 $(I_C = -1A)$

• High Speed Switching Time: $t_{stg} = 300ns$ (Typ.)

• Small Flat Package

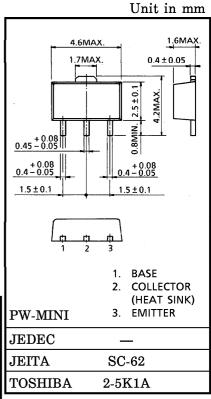
• P_C=1~2W (Mounted on Ceramic Substrate)

• Complementary to 2SC4409

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	-60	V
Collector-Emitter Voltage	v_{CEO}	-50	v
Emitter-Base Voltage	$V_{ m EBO}$	-6	V
Collector Current	$I_{\mathbf{C}}$	-2	Α
Base Current	$I_{\mathbf{B}}$	-0.2	Α
Collector Power Dissipation	$P_{\mathbf{C}}$	500	mW
Collector Power Dissipation	PC*	1000	mW
Junction Temperature	$T_{\rm j}$	150	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

^{* :} Mounted on ceramic substrate (250mm $^2 \times 0.8t$)



Weight: 0.05g (Typ.)

Marking

Type Name

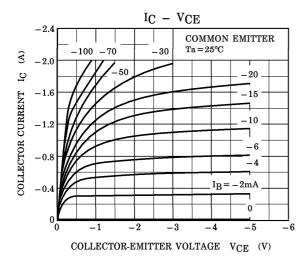


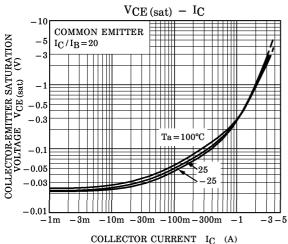
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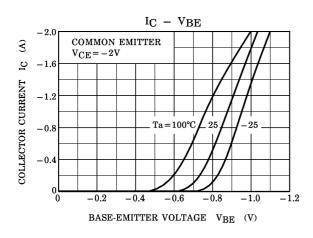
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

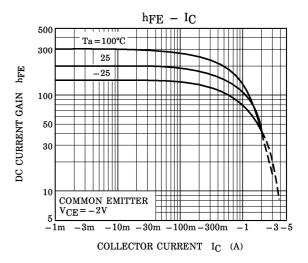
CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-	off Current	I_{CBO}	$V_{CB} = -60V, I_{E} = 0$	_	_	-0.1	μ A
Emitter Cut-of	ff Current	I_{EBO}	$V_{EB} = -6V, I_C = 0$	_	_	-0.1	μ A
Collector-Emit Breakdown Vo		V (BR) CEO	$I_{C} = -10 \text{mA}, I_{B} = 0$	-50	_	_	V
DC Current Gain		h _{FE (1)}	$V_{CE} = -2V, I_{C} = -100 mA$	120	_	400	-
		h _{FE (2)}	$V_{CE} = -2V, I_{C} = -1.5A$	40	_	_	
Collector-Emit Saturation Vo.		V _{CE} (sat)	$I_C = -1A, I_B = -0.05A$	_	_	-0.5	v
Base-Emitter Saturation Vol	ltage	V _{BE} (sat)	$I_C = -1A, I_B = -0.05A$	_	_	-1.2	V
Transition Fre	quency	$\mathbf{f_T}$	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	_	100	_	MHz
Collector Output Capacitance		C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$	_	23		pF
Switching Time	Turn-on Time	ton	$\begin{array}{c c} I_{B2} & I_{B2} & \text{OUTPUT} \\ I_{B1} & I_{NPUT} & I_{B1} & \text{C} \\ I_{B1} = I_{B2} = 0.05 \text{A} \\ \text{DUTY CYCLE} \leq 1\% \end{array} -30 \text{V}$	_	0.1	_	
	Storage Time	t_{stg}		_	0.3	_	μ s
	Fall Time	tf		_	0.1	_	

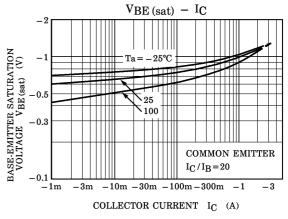
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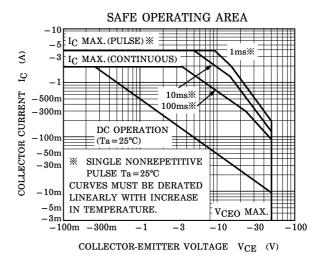












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